

# CD4016B Types

## CMOS Quad Bilateral Switch

For Transmission or Multiplexing of Analog or Digital Signals

High-Voltage Types (20-Volt Rating)

■ CD4016B Series types are quad bilateral switches intended for the transmission or multiplexing of analog or digital signals. Each of the four independent bilateral switches has a single control signal input which simultaneously biases both the p and n device in a given switch on or off.

The CD4016 "B" Series types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PWR and PWR suffixes).

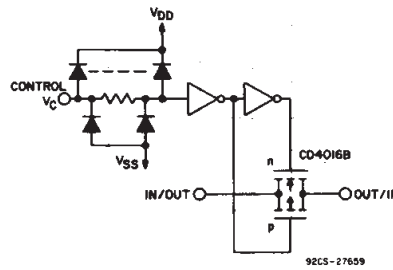
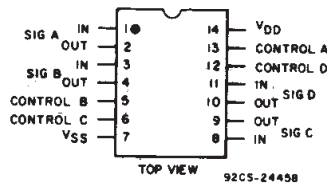
### Features:

- 20-V digital or  $\pm 10$ -V peak-to-peak switching
- $280\text{-}\Omega$  typical on-state resistance for 15-V operation
- Switch on-state resistance matched to within 10  $\Omega$  typ. over 15-V signal-input range
- High on/off output-voltage ratio: 65 dB typ. @  $f_{is} = 10$  kHz,  $R_L = 10$  k $\Omega$
- High degree of linearity: <0.5% distortion typ. @  $f_{is} = 1$  kHz,  $V_{is} = 5$  V<sub>p-p</sub>,  $V_{DD} - V_{SS} \geq 10$  V,  $R_L = 10$  k $\Omega$
- Extremely low off-state leakage resulting in very low offset current and high effective off-state resistance: 100 pA typ. @  $V_{DD} - V_{SS} = 18$  V,  $T_A = 25^\circ\text{C}$
- Extremely high control input impedance (control circuit isolated from signal circuit): 1012  $\Omega$  typ.
- Low crosstalk between switches: -50 dB typ. @  $f_{is} = 0.9$  MHz,  $R_L = 1$  k $\Omega$
- Matched control-input to signal-output capacitance: Reduces output signal transients
- Frequency response, switch on = 40 MHz (typ.)
- 100% tested for quiescent current at 20 V
- Maximum control input current of 1  $\mu\text{A}$  at 18 V over full package temperature range; 100 nA at 18 V at 25 $^\circ\text{C}$
- 5-V, 10-V, and 15-V parametric ratings

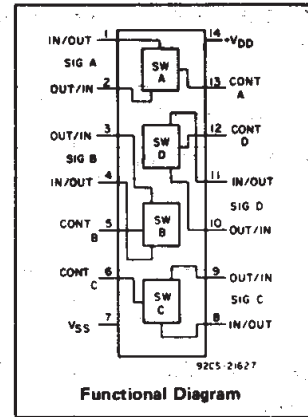
### Applications:

- Analog signal switching/multiplexing
  - Signal gating                      ■ Modulator
  - Squelch control                    ■ Demodulator
  - Chopper                              ■ Commutating switch
- Digital signal switching/multiplexing
- CMOS logic implementation
- Analog-to-digital & digital-to-analog conversion
- Digital control of frequency, impedance, phase, and analog-signal gain

### Terminal Assignment



Schematic diagram - 1 of 4 identical sections.



### RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following range:

CHARACTERISTIC	LIMITS		UNITS
	Min.	Max.	
Supply Voltage Range (For $T_A =$ Full Package Temperature Range)	3	18	V

### MAXIMUM RATINGS, Absolute-Maximum Values:

- DC SUPPLY-VOLTAGE RANGE, ( $V_{DD}$ ) Voltages referenced to  $V_{SS}$  Terminal) ..... -0.5V to +20V
- INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to  $V_{DD} + 0.5$ V
- DC INPUT CURRENT, ANY ONE INPUT .....  $\pm 10$ mA
- POWER DISSIPATION PER PACKAGE ( $P_D$ ):
  - For  $T_A = -55^\circ\text{C}$  to  $+100^\circ\text{C}$  ..... 500mW
  - For  $T_A = +100^\circ\text{C}$  to  $+125^\circ\text{C}$  ..... Derate Linearly at 12mW/ $^\circ\text{C}$  to 200mW
- DEVICE DISSIPATION PER OUTPUT TRANSISTOR
  - FOR  $T_A =$  FULL PACKAGE-TEMPERATURE RANGE (All Package Types) ..... 100mW
- OPERATING-TEMPERATURE RANGE ( $T_A$ ) .....  $-55^\circ\text{C}$  to  $+125^\circ\text{C}$
- STORAGE TEMPERATURE RANGE ( $T_{stg}$ ) .....  $-65^\circ\text{C}$  to  $+150^\circ\text{C}$
- LEAD TEMPERATURE (DURING SOLDERING):
  - At distance  $1/16 \pm 1/32$  inch ( $1.59 \pm 0.79$ mm) from case for 10s max .....  $+265^\circ\text{C}$

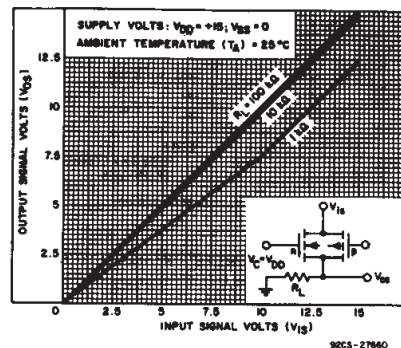


Fig. 1— Typ. on-state characteristics for 1 of 4 switches with  $V_{DD} = +15$  V,  $V_{SS} = 0$  V.

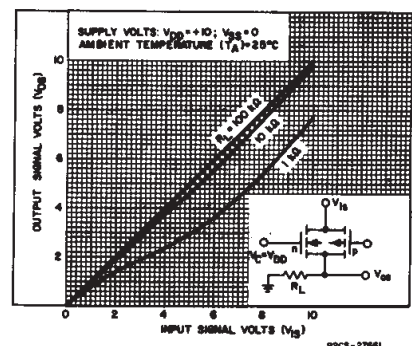


Fig. 2— Typ. on-state characteristics for 1 of 4 switches with  $V_{DD} = +10$  V,  $V_{SS} = 0$  V.

# CD4016B Types

## ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS	LIMITS AT INDICATED TEMPERATURES (°C)							UNITS	
		V <sub>IN</sub> (V)	V <sub>DD</sub> (V)					+25		
				-55	-40	+85	+125	Typ.		Max.
Quiescent Device Current, I <sub>DD</sub>		0,5	5	0,25	0,25	7,5	7,5	0,01	0,25	μA
		0,10	10	0,5	0,5	15	15	0,01	0,5	
		0,15	15	1	1	30	30	0,01	1	
		0,20	20	5	5	150	150	0,02	5	
Signal Inputs (V <sub>is</sub> ) and Output (V <sub>os</sub> )										
On-State Resistance, r <sub>on</sub> Max.	V <sub>C</sub> = V <sub>DD</sub> R <sub>L</sub> = 10 kΩ Returned to V <sub>DD</sub> - V <sub>SS</sub> 2	V <sub>is</sub> = V <sub>DD</sub> or V <sub>SS</sub>	10	600	610	840	960	-	660	Ω
		V <sub>is</sub> = 4.75 to 5.75 V	10	1870	1900	2380	2600	-	2000	
Δ On-State Resistance Between Any 2 Switches, Δr <sub>on</sub>	R <sub>L</sub> = 10 kΩ, V <sub>C</sub> = V <sub>DD</sub>	V <sub>is</sub> = V <sub>DD</sub> or V <sub>SS</sub>	15	360	370	520	600	-	400	Ω
		V <sub>is</sub> = 7.25 to 7.75 V	15	775	790	1080	1230	-	850	
			5	-	-	-	-	15	-	
Total Harmonic Distortion, THD	V <sub>C</sub> = V <sub>DD</sub> = 5 V, V <sub>SS</sub> = -5 V, V <sub>is</sub> (p-p) = 5 V (Sine wave centered on 0 V) R <sub>L</sub> = 10 kΩ, f <sub>is</sub> = 1 kHz sine wave		-	-	-	-	0.4	-	%	
-3dB Cutoff Frequency (Switch on)	V <sub>C</sub> = V <sub>DD</sub> = 5 V, V <sub>SS</sub> = -5 V, V <sub>is</sub> (p-p) = 5 V (Sine wave centered on 0 V) R <sub>L</sub> = 1 kΩ.		-	-	-	-	40	-	MHz	
-50dB Feed-through Frequency (Switch off)	V <sub>C</sub> = V <sub>SS</sub> = -5 V, V <sub>is</sub> (p-p) = 5 V (Sine wave centered on 0 V) R <sub>L</sub> = 1 kΩ		-	-	-	-	1.25	-	MHz	
Input/Output Leakage Current (Switch off) I <sub>is</sub> Max.	V <sub>C</sub> = 0 V V <sub>is</sub> = 18 V, V <sub>os</sub> = 0 V; V <sub>is</sub> = 0 V, V <sub>os</sub> = 18 V	18	±0.1	±0.1	±1	±1	10 <sup>-4</sup>	±0.1	μA	
-50 dB Crosstalk Frequency	V <sub>C</sub> (A) = V <sub>DD</sub> = +5 V, V <sub>C</sub> (B) = V <sub>SS</sub> = -5 V, V <sub>is</sub> (A) = 5 V p-p, 50 Ω source R <sub>L</sub> = 1 kΩ		-	-	-	-	0.9	-	MHz	
Propagation Delay (Signal Input to Signal Output) t <sub>pd</sub>	R <sub>L</sub> = 200 kΩ V <sub>C</sub> = V <sub>DD</sub> , V <sub>SS</sub> = GND, C <sub>L</sub> = 50 pF V <sub>is</sub> = Square Wave 0 to V <sub>DD</sub> t <sub>r</sub> , t <sub>f</sub> = 20 ns	5	-	-	-	-	40	100	ns	
		10	-	-	-	-	20	40		
		15	-	-	-	-	15	30		
Capacitance: Input, C <sub>is</sub> Output, C <sub>os</sub> Feedthrough, C <sub>ios</sub>	V <sub>DD</sub> = +5 V V <sub>C</sub> = V <sub>SS</sub> = -5 V		-	-	-	-	4	-	pF	
			-	-	-	-	4	-		
			-	-	-	-	0.2	-		

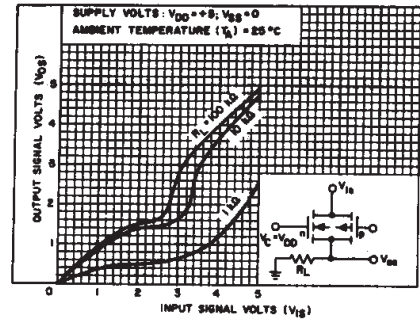


Fig. 3—Typ. on-state characteristics for 1 of 4 switches with V<sub>DD</sub> = +5 V, V<sub>SS</sub> = 0 V.

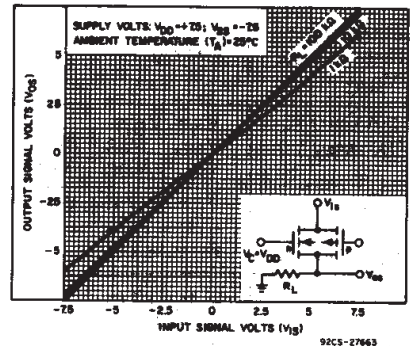


Fig. 4—Typ. on-state characteristics for 1 of 4 switches with V<sub>DD</sub> = +7.5 V, V<sub>SS</sub> = -7.5 V.

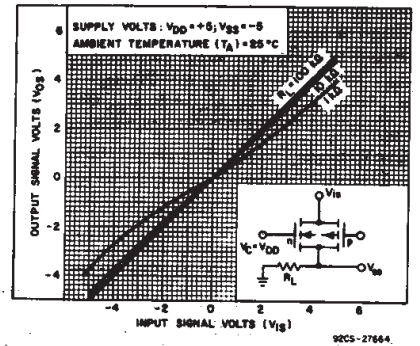


Fig. 5—Typ. on-state characteristics for 1 of 4 switches with V<sub>DD</sub> = +5 V, V<sub>SS</sub> = -5 V.

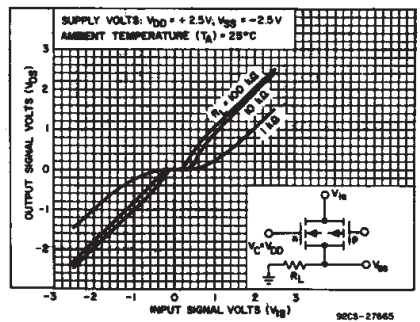


Fig. 6—Typ. on-state characteristics for 1 of 4 switches with V<sub>DD</sub> = +2.5 V, V<sub>SS</sub> = -2.5 V.

3  
COMMERCIAL CMOS  
HIGH VOLTAGE ICs

# CD4016B Types

## ELECTRICAL CHARACTERISTICS (cont'd)

CHARACTERISTIC	TEST CONDITIONS	LIMITS AT INDICATED TEMPERATURES (°C)						UNITS	
		V <sub>DD</sub> (V)		+25					
		-55	-40	+85	+125	Typ.	Max.		
<b>Control (V<sub>C</sub>)</b>									
Control Input Low Voltage, V <sub>ILC</sub> (Max.)	I <sub>is</sub> < 10 μA V <sub>is</sub> = V <sub>SS</sub> , V <sub>OS</sub> = V <sub>DD</sub> and V <sub>is</sub> = V <sub>DD</sub> , V <sub>OS</sub> = V <sub>SS</sub>	5, 10, 15	0.9	0.9	0.4	0.4	-	0.7	V
Control Input High Voltage, V <sub>IHC</sub>	See Fig. 10	5, 10, 15	3.5 (Min.) 7 (Min.) 11 (Min.)						V
Input Current, I <sub>IN</sub> (Max.)	V <sub>is</sub> ≤ V <sub>DD</sub> V <sub>DD</sub> - V <sub>SS</sub> = 18 V V <sub>CC</sub> ≤ V <sub>DD</sub> - V <sub>SS</sub>	18	±0.1	±0.1	±1	±1	±10 <sup>-5</sup>	±0.1	μA
Crosstalk (Control Input to Signal Output)	V <sub>C</sub> = 10 V (Sq. Wave) t <sub>r</sub> , t <sub>f</sub> = 20 ns R <sub>L</sub> = 10 kΩ	10	-	-	-	-	50	-	mV
Turn-On Propagation Delay	t <sub>r</sub> , t <sub>f</sub> = 20 ns C <sub>L</sub> = 50 pF R <sub>L</sub> = 1 kΩ	5, 10, 15	-	-	-	-	35, 20, 15	70, 40, 30	ns
Maximum Control Input Repetition Rate	V <sub>is</sub> = V <sub>DD</sub> , V <sub>SS</sub> = GND, R <sub>L</sub> = 1 kΩ to gnd, C <sub>L</sub> = 50 pF, V <sub>C</sub> = 10 V (Square wave centered on 5 V) t <sub>r</sub> , t <sub>f</sub> = 20 ns, V <sub>os</sub> = ½ V <sub>os</sub> @ 1 kHz	10	-	-	-	-	10	-	MHz
Input Capacitance, C <sub>IN</sub>			-	-	-	-	5	7.5	μF

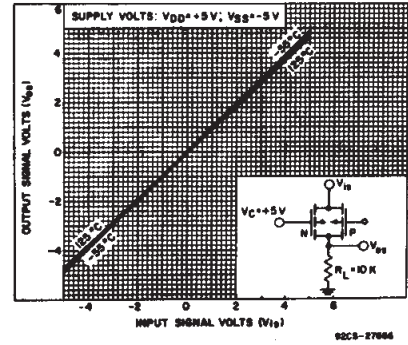


Fig. 7—Typ. on-state characteristics as a function of temp. for 1 of 4 switches with V<sub>DD</sub> = +5 V, V<sub>SS</sub> = -5 V.

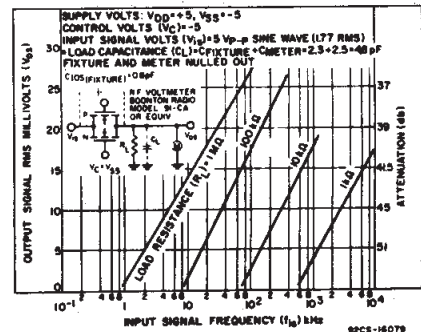


Fig. 8—Typ. feedthrough vs. frequency—switch off.

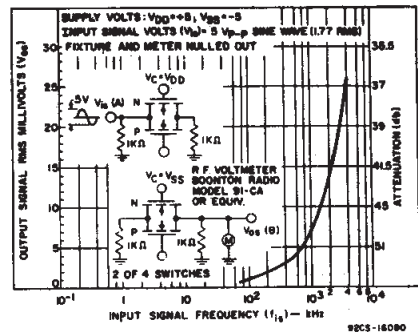


Fig. 9—Typical crosstalk between switch circuits in the same package.

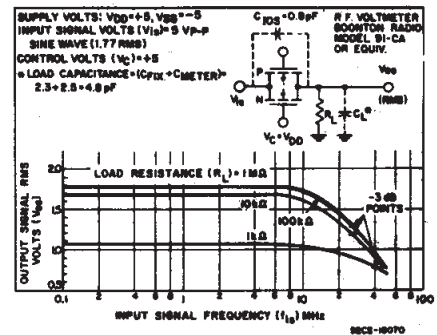


Fig. 11—Typical frequency response—switch on.

V <sub>DD</sub> (V)	V <sub>is</sub> (V)	Switch Input I <sub>is</sub> (mA)						Switch Output V <sub>os</sub> (V)	
		-55°C	-40°C	25°C*	25°C▲	+85°C	+125°C	Min.	Max.
5	0	0.25	0.2	0.2	0.16	0.12	0.14	-	0.4
5	5	-0.25	-0.2	-0.2	-0.16	-0.12	-0.14	4.6	-
10	0	0.62	0.5	0.5	0.4	0.3	0.35	-	0.5
10	10	-0.62	-0.5	-0.5	-0.4	-0.3	-0.35	9.5	-
15	0	1.8	1.4	1.5	1.2	1	1.1	-	1.5
15	15	-1.8	-1.4	-1.5	-1.2	-1	-1.1	13.5	-

\* Plastic package

▲ Ceramic package

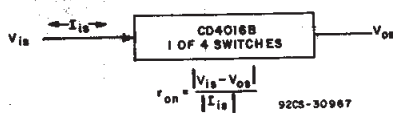


Fig. 10—Determination of r<sub>on</sub> as a test condition for control input high voltage (V<sub>IHC</sub>) specification.

# CD4016B Types

## TYPICAL ON-STATE RESISTANCE CHARACTERISTICS, $T_A = 25^\circ\text{C}$

CHARACTERISTIC*	SUPPLY CONDITIONS		LOAD CONDITIONS					
			$R_L = 1k\Omega$		$R_L = 10k\Omega$		$R_L = 100k\Omega$	
	$V_{DD}$ (V)	$V_{SS}$ (V)	VALUE ( $\Omega$ )	$V_{IS}$ (V)	VALUE ( $\Omega$ )	$V_{IS}$ (V)	VALUE ( $\Omega$ )	$V_{IS}$ (V)
$r_{on}$	+15	0	200	+15	200	+15	180	+15
$r_{on}$ (max.)	+15	0	200	0	200	0	200	0
$r_{on}$	+10	0	290	+10	250	+10	240	+10
$r_{on}$ (max.)	+10	0	290	0	250	0	300	0
$r_{on}$	+5	0	860	+5	470	+5	450	+5
$r_{on}$ (max.)	+5	0	600	0	580	0	800	0
$r_{on}$	+7.5	-7.5	200	+7.5	200	+7.5	180	+7.5
$r_{on}$ (max.)	+7.5	-7.5	290	$\pm 0.25$	280	$\pm 25$	400	$\pm 0.25$
$r_{on}$	+5	-5	260	+5	250	+5	240	+5
$r_{on}$ (max.)	+5	-5	310	-5	250	-5	240	-5
$r_{on}$	+2.5	-2.5	590	+2.5	450	+2.5	490	+2.5
$r_{on}$ (max.)	+2.5	-2.5	720	-2.5	520	-2.5	520	-2.5
$r_{on}$	+2.5	-2.5	232k	$\pm 0.25$	300k	$\pm 0.25$	870k	$\pm 0.25$

\* Variation from perfect switch,  $r_{on} = 0 \Omega$ .

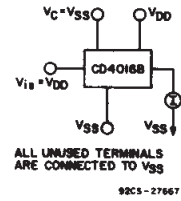


Fig. 12 – Off-state switch input or output leakage current test circuit.

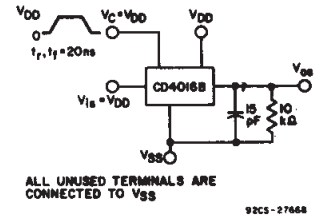
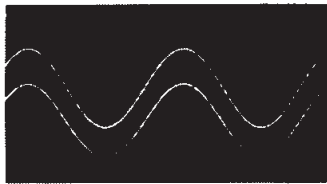


Fig. 13 – Test circuit for square-wave response.



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV  
 $V_{DD} = V_C = +7.5V, V_{SS} = -7.5V, R_L = 10K\Omega$   
 $C_L = 15 pF$   
 $f_{IS} = 1 KHz, V_{IS} = 5V p-p$   
 DISTORTION = 0.2 %

92CS-27612

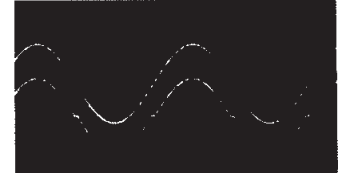
Fig. 14 – Typical sine wave response of  $V_{DD} = +7.5 V, V_{SS} = -7.5 V$ .



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV  
 $V_{DD} = V_C = +5V, V_{SS} = -5V, R_L = 10K\Omega$   
 $C_L = 15 pF$   
 $f_{IS} = 1 KHz, V_{IS} = 5V p-p$   
 DISTORTION = 0.4 %

92CS-27613

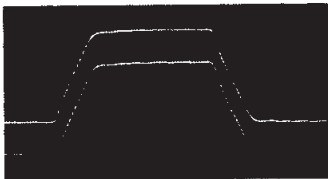
Fig. 15 – Typical sine wave response of  $V_{DD} = +5 V, V_{SS} = -5 V$ .



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV  
 $V_{DD} = V_C = +2.5V, V_{SS} = -2.5V, R_L = 10K\Omega$   
 $C_L = 15 pF$   
 $f_{IS} = 1 KHz, V_{IS} = 5V p-p$   
 DISTORTION = 3 %

92CS-27614

Fig. 16 – Typical sine wave response of  $V_{DD} = +2.5 V, V_{SS} = -2.5 V$ .



SCALE: X = 100 ns/DIV  
 Y = 5.0 V/DIV

92CS-27615

Fig. 17 – Typical square wave response at  $V_{DD} = V_C = +15 V, V_{SS} = Gnd$ .



SCALE: X = 100 ns/DIV  
 Y = 5.0 V/DIV

92CS-27616

Fig. 18 – Typical square wave response at  $V_{DD} = V_C = +10 V, V_{SS} = Gnd$ .



SCALE: X = 100 ns/DIV  
 Y = 2 V/DIV

92CS-27617

Fig. 19 – Typical square wave response at  $V_{DD} = V_C = +5 V, V_{SS} = Gnd$ .

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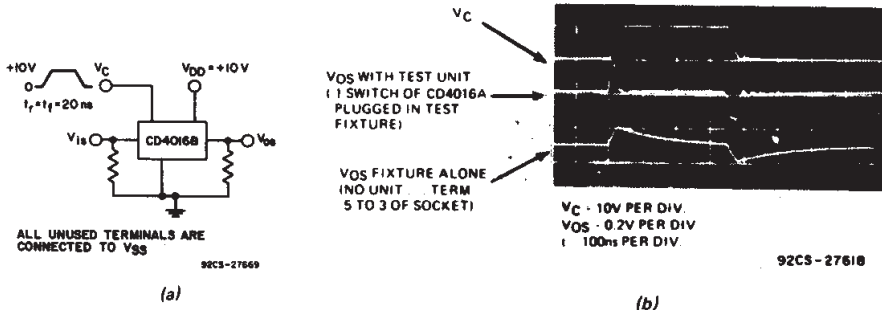


Fig. 20 - Crosstalk-control input to signal output.

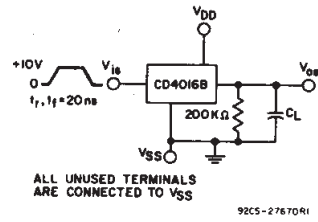


Fig. 21 - Propagation delay time signal input ( $V_{is}$ ) to signal output ( $V_{os}$ ).

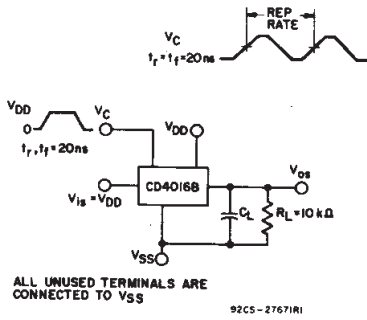


Fig. 22 - Max. control-input repetition rate.

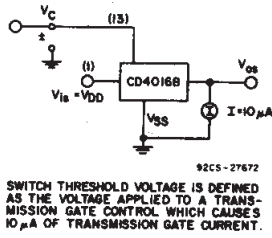


Fig. 23 - Switch threshold voltage.

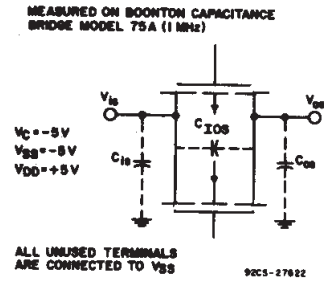


Fig. 24 - Capacitance  $C_{IOs}$  and  $C_{OS}$ .

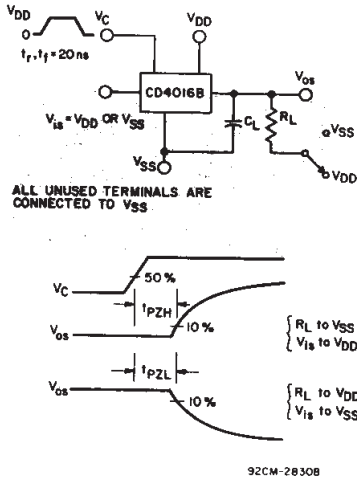
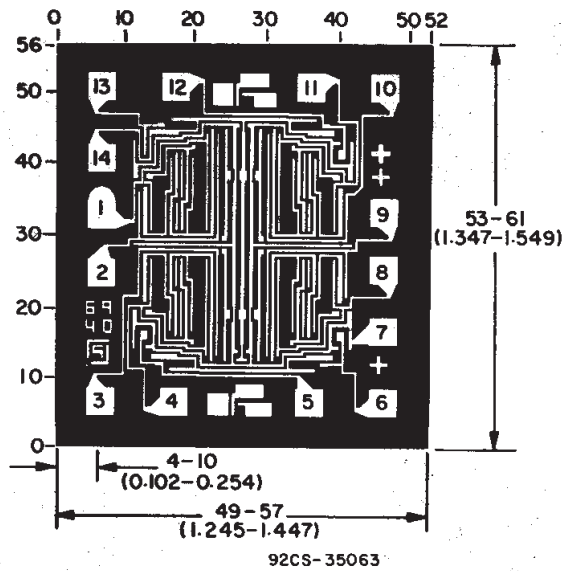


Fig. 25 - Turn-On propagation delay-control input.

## Dimensions and pad layout for CD4016BH



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-9064001CA	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD4016BE	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4016BEE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4016BF	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD4016BF3A	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD4016BM	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BM96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BM96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BM96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BMG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BMT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BMTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BMTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BNSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BNSRE4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BNSRG4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BPWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BPWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BPWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4016BPWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

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**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**TAPE AND REEL INFORMATION**



**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4016BM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4016BNSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4016BPWR	TSSOP	PW	14	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1



**TAPE AND REEL BOX DIMENSIONS**



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4016BM96	SOIC	D	14	2500	346.0	346.0	33.0
CD4016BNSR	SO	NS	14	2000	346.0	346.0	33.0
CD4016BPWR	TSSOP	PW	14	2000	346.0	346.0	29.0

# MECHANICAL DATA

NS (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

J (R-GDIP-T\*\*)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

- NOTES:
- All linear dimensions are in inches (millimeters).
  - This drawing is subject to change without notice.
  - This package is hermetically sealed with a ceramic lid using glass frit.
  - Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
  - Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

PW (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153

D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
  - E. Reference JEDEC MS-012 variation AB.

N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\triangle C$  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - $\triangle D$  The 20 pin end lead shoulder width is a vendor option, either half or full width.

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